MJL0281A (NPN) MJL0302A (PNP)

Preferred Devices

Complementary NPN-PNP Power Bipolar Transistors

These complementary devices are lower power versions of the popular MJL3281A and MJL1302A audio output transistors. With superior gain linearity and safe operating area performance, these transistors are ideal for high fidelity audio amplifier output stages and other linear applications.

Features

- Exceptional Safe Operating Area
- NPN/PNP Gain Matching within 10% from 50 mA to 3.0 A
- Excellent Gain Linearity
- High BVCEO
- High Frequency
- Pb–Free Packages are Available*

Benefits

- Reliable Performance at Higher Powers
- Symmetrical Characteristics in Complementary Configurations
- Accurate Reproduction of Input Signal
- Greater Dynamic Range
- High Amplifier Bandwith

Applications

- High-End Consumer Audio Products
 - Home Amplifiers
 - Home Receivers
- Professional Audio Amplifiers
 - Theater and Stadium Sound Systems
 - Public Address Systems (PAs)

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	260	Vdc
Collector-Base Voltage	V _{CBO}	260	Vdc
Emitter-Base Voltage	V _{EBO}	5.0	Vdc
Collector-Emitter Voltage - 1.5 V	V _{CEX}	260	Vdc
Collector Current – Continuous – Peak (Note 1)	Ι _C	15 30	Adc
Base Current – Continuous	Ι _Β	1.5	Adc
Total Power Dissipation @ $T_C = 25^{\circ}C$	PD	180	Watts
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability. 1. Pulse Test: Pulse Width = 5.0 ms, Duty Cycle < 10%.



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15 AMPERES COMPLEMENTARY SILICON POWER TRANSISTORS 260 VOLTS – 180 WATTS



Device	Package	Shipping
MJL0281A	TO-264	25 Units/Rail
MJL0281AG	TO–264 (Pb–Free)	25 Units/Rail
MJL0302A	TO-264	25 Units/Rail
MJL0302AG	TO–264 (Pb–Free)	25 Units/Rail

Preferred devices are recommended choices for future use and best overall value.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.69	°C/W

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS			•	
Collector–Emitter Sustaining Voltage $(I_C = 30 \text{ mA}, I_B = 0)$	V _{CEO(sus)}	260	-	V
Collector Cutoff Current ($V_{CB} = 260 \text{ V}, I_E = 0$)	Ісво	-	10	μΑ
Emitter Cutoff Current ($V_{EB} = 5.0 \text{ V}, I_C = 0$)	I _{EBO}	-	5.0	μΑ
ON CHARACTERISTICS				
DC Current Gain $(I_C = 0.5 \text{ A}, V_{CE} = 5.0 \text{ V})$ $(I_C = 1.0 \text{ A}, V_{CE} = 5.0 \text{ V})$ $(I_C = 3.0 \text{ A}, V_{CE} = 5.0 \text{ V})$	h _{FE}	75 75 75	150 150 150	_
Collector–Emitter Saturation Voltage $(I_C = 5.0 \text{ A}, I_B = 0.5 \text{ A})$	V _{CE(sat)}	-	1.0	V
Base–Emitter On Voltage ($I_C = 5.0 \text{ A}, V_{CE} = 5.0 \text{ V}$)	V _{BE(on)}	_	1.2	V
DYNAMIC CHARACTERISTICS				
Current–Gain – Bandwidth Product ($I_C = 1.0 \text{ A}, V_{CE} = 5.0 \text{ V}, f_{test} = 1.0 \text{ MHz}$)	f _T	30	-	MHz
Output Capacitance (V_{CB} = 10 V, I _E = 0, f _{test} = 1.0 MHz)	C _{ob}	_	400	pF



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PACKAGE DIMENSIONS

TO-3BPL (TO-264) CASE 340G-02 ISSUE J



	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	28.0	29.0	1.102	1.142
В	19.3	20.3	0.760	0.800
С	4.7	5.3	0.185	0.209
D	0.93	1.48	0.037	0.058
Е	1.9	2.1	0.075	0.083
F	2.2	2.4	0.087	0.102
G	5.45 BSC		0.215 BSC	
н	2.6	3.0	0.102	0.118
J	0.43	0.78	0.017	0.031
ĸ	17.6	18.8	0.693	0.740
L	11.2 REF		0.411 REF	
N	4.35 REF		0.172 REF	
Р	2.2	2.6	0.087	0.102
Q	3.1	3.5	0.122	0.137
R	2.25 REF		0.089 REF	
U	6.3 REF		0.248 REF	
w	2.8	3.2	0.110	0.125

1. DIMENSIONING AND TOLERANCING PER



NOTES

3. EMITTER

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